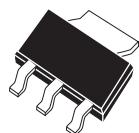


**CZSH-4**  
**SURFACE MOUNT**  
**SILICON SCHOTTKY**  
**BARRIER RECTIFIER**



**SOT-223 CASE**

**Central**<sup>TM</sup>  
**Semiconductor Corp.**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CZSH-4 type is a schottky barrier rectifier mounted in an epoxy molded case using a metal to silicon junction to yield low forward voltage drop. The anode connections are made to PIN 1 and PIN 3.

**MARKING CODE: FULL PART NUMBER**

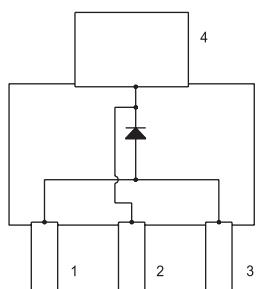
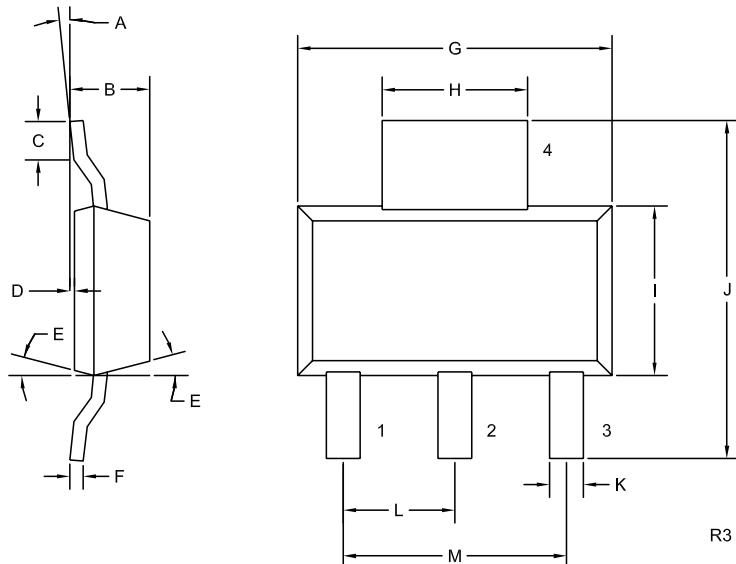
**MAXIMUM RATINGS (T<sub>A</sub>=25°C)**

	<b>SYMBOL</b>		<b>UNITS</b>
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	40	V
DC Blocking Voltage	V <sub>R</sub>	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Forward Current	I <sub>O</sub>	2.0	A
Peak Forward Surge Current (8.3ms, Non-Rep.)	I <sub>FSM</sub>	10	A
Operating and Storage Junction Temperature	T <sub>J,Tstg</sub>	-65 to +150	°C

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise noted)**

<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>MAX</b>	<b>UNITS</b>
I <sub>R</sub>	V <sub>R</sub> =40V		1.0	mA
I <sub>R</sub>	V <sub>R</sub> =40V, T <sub>A</sub> =100°C		10	mA
V <sub>F</sub>	I <sub>F</sub> =1.0A		0.55	V
V <sub>F</sub>	I <sub>F</sub> =2.0A		0.60	V

SOT-223 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS		INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX	MIN	MAX
A	0°	10°	0°	10°		
B	0.059	0.071	1.50	1.80		
C	0.018	---	0.45	---		
D	0.000	0.004	0.00	0.10		
E	15°		15°			
F	0.009	0.014	0.23	0.35		
G	0.248	0.264	6.30	6.70		
H	0.114	0.122	2.90	3.10		
I	0.130	0.146	3.30	3.70		
J	0.264	0.287	6.70	7.30		
K	0.024	0.033	0.60	0.85		
L	0.091		2.30			
M	0.181		4.60			

SOT-223 (REV: R3)

**LEAD CODE:**

- 1) ANODE
- 2) CATHODE
- 3) ANODE
- 4) CATHODE

**MARKING CODE:**

FULL PART NUMBER

R5 (17-June 2004)